Analysis of Resonance Response Performance of C-Band Antenna Using Parasitic Element

M. R. Zaman, 1 M. T. Islam, 2 N. Misran, 2 and J. S. Mandep 2

1 Centre for Space Science (ANGKASA), Universiti Kebangsaan Malaysia (UKM), Bangi 43600, Malaysia
2 Department of Electrical, Electronic and Systems Engineering, Faculty of Engineering and Built Environment, Universiti Kebangsaan Malaysia (UKM), Bangi 43600, Malaysia

Correspondence should be addressed to M. T. Islam; titareq@gmail.com

Received 5 March 2014; Revised 8 April 2014; Accepted 9 April 2014; Published 6 May 2014

1. Introduction

It is a major concern for today’s antenna designer to improve the antenna characteristics at given bands to work in. A lot of research is being conducted to make compact antennae for the ease of use. For compactness and lightweight, microstrip antenna is becoming famous among researchers day by day all over the world [1]. As a new trend in microstrip antenna research, use of parasitic elements in antenna configuration has opened a new doorway within the field. The use of parasitic element is not explored much for C-band (4–8 GHz) [2–4]. A planar monopulse array antenna for C-band is shown in [5]. The antenna has a high array gain. Nonetheless, it is a multilayered antenna structure with an overall dimension of 210 × 210 mm². A C-band antenna using electromagnetic band gap (EBG) structure is shown in [6]. This antenna consists of dual circular polarization. However, the antenna has a superstrate dimension of 365 × 365 mm² which is bulky for C-band application. A diode controlled dual band antenna for C-band is shown in [7]. The antenna uses a complex structure to connect the diode with the main body and attain dual band response. A band-notched antenna design method for UWB applications is shown in [8] that includes two parasitic elements at both sides of the active element to have band notch characteristic. Additionally the bottom layer has the same parasitic element with same dimensions. However, the gain of the antenna is comparatively adverse at the lower band. Another antenna is shown with four rectangular sized parasitic elements in [9]. The parasitic elements are required to achieve notch within the passband of the antenna. While optimizing using genetic algorithm, two parasitic elements were included to increase the bandwidth performance of the antenna in [10]. A slot is designed to act as a parasitic element for higher frequencies to increase the bandwidth and efficiency in [11]. By coupling with the monopole structure, the slot acts as a parasitic element. Nonetheless, the gain theta (θ) at the radiation pattern seems to increase more than gain phi (φ) when φ = 90° at higher frequencies. A bandwidth increment method is shown in [12] using proximity feeding technique. Among two antennas designed, one of the antennas has two square parasitic elements coupled with the proximity-fed antenna to increase the bandwidth. In spite of that, to increase antenna gain, the antenna has to compromise omnidirectional radiation pattern. A dual
The proposed microstrip antenna is compact in size and square shaped with a dimension of $80 \times 80 \text{mm}^2$. Current distributions are exhibited and studied to demonstrate the coupling technique. Finally, the proposed antenna is fabricated and measured to validate the findings.

2. Antenna Design

The proposed antenna is designed using FR4 substrate with a relative permittivity of 4.6 and a thickness of $h = 1.6 \text{ mm}$. The effective relative permittivity is calculated using

$$\varepsilon_e = \frac{\varepsilon_r + 1}{2} + \frac{\varepsilon_r - 1}{2(\sqrt{12h/X} + 1)}.$$  \hspace{1cm} (1)$$

Here, $\varepsilon_r$ = relative permittivity, $h$ = substrate height, and $X$ = strip width. The proposed antenna has a parasitic circle at the middle of the structure shown in Figure 1(a). A feed line of $15 \text{ mm}$ length and $5 \text{ mm}$ width is connected with a $50 \Omega$ port along with a bended line of length $49.25 \text{ mm}$ at the upper edge of the feed line. The bended line creates a coupling with the parasitic circle element. Another passive microstrip line is at the other side of the circle with a length of $50 \text{ mm}$. The ground plane shown in Figure 1(b) is rectangular shaped with the size of $80 \text{ mm}$ in length and $30 \text{ mm}$ in width. The total antenna dimension is $80 \times 80 \times 1.6 \text{ mm}^3$. The height of the antenna is $1.6 \text{ mm}$; it is very small compared to the length and width of the antenna. The fields along z axis direction are quite unlikely to change with negligible height. The mode for the resonant frequencies $f_{mn0}$ can be found by using [24]

$$f_{mn0} = \frac{X_{mn}}{2\pi \times R_c \times \sqrt{\varepsilon_e}},$$

$$R_c = R \sqrt{\left[1 + 2 \times \frac{h}{2 \varepsilon_r \pi} \times \ln\left(\frac{R\pi}{2h}\right) + 1.7726\right]}.$$  \hspace{1cm} (2)$$

Here, $X_{mn} = 0$ of the derivative of the Bessel Function, $R_c$ = effective radius of the patch, and $\varepsilon_e$ = effective relative permittivity.

Figure 2 shows the fabricated antenna in FR4 substrate. The antenna is fed by a SMA coaxial connector with input impedance of $50 \Omega$. The dimensions of the antenna are shown in Table 2.

Partial coupling is introduced using the microstrip line connected with the feed line. The coupling intensity is measured using the equation depended on the gap [25] between the parasitic circle and the tapered microstrip resonator. Using series capacitor, the equivalent circuit can be constructed as shown in Figure 3 for the gap in between microstrip lines. After ignoring the fringing fields the capacitor value can be calculated as

$$C = \frac{b_k}{\omega Z_0},$$  \hspace{1cm} (3)$$

where $C$ = coupling capacitor, $b_k$ = normalized coupling capacitor susceptance, and $Z_0$ = characteristics impedance. A negligible coupling grows between the two microstrip lines.
Figure 1: (a) Dimensions of the antenna patch and (b) dimensions of the antenna ground plane.

Figure 2: (a) Patch and (b) ground plane of the fabricated antenna prototype.

Figure 3: Equivalent circuit of the microstrip gap coupling.

situated at the top and bottom side of the antenna. A sharp edge banding after the feed line is performed to have better resonance at the first resonance frequency.

3. Antenna Parameters Analysis

To validate the proposed design and optimize the antenna structure, parametric analysis is performed. The major parts of the structure which are responsible for changing the S-parameter response of the antenna are modified to get the following parametric studies. This study will help to investigate the change in the impedance bandwidth along with the reflection coefficient. The main goal of this antenna is to achieve a coupling performance from two parasitic elements and analyze the coupling between them. The antenna is designed using FR4 substrate to achieve cost effectiveness and durability. With the use of RT/duroid substrate, the performance of the antenna can be enhanced; in this case decreasing the total fabrication cost is one of the main targets.
The thickness of the FR4 substrate is preselected which is 1.6 mm. The thickness is chosen to make the antenna durable and applicable for outside applications. Figure 4 shows the $S_{11}$ response of the antenna for the parametric change in the radius "R" of the circle situated right in the middle of the antenna patch structure. The circle creates a coupling connection with the parasitic line above and the active line below. By changing the radius of the circle, the coupling effect between them changes and hence as a result the change in $S_{11}$ can be seen in Figure 4. In this figure, a notch is introduced at 5.7 GHz, whereas the second resonance is still the same for the change in radius for $R = 12$ mm. The second resonance at 7.6 GHz shifts about 25 MHz below 7.6 GHz, where for the first resonance a notch is introduced at $R = 13$ mm. At $R = 14$ mm, the first resonance is shifted about 200 MHz above the desired resonance frequency. Also the first resonance response has become narrower, whereas the second resonance response stays the same. By using $R = 15$ mm, both of the resonance frequencies are found without any notch at the operating frequencies with a wide impedance bandwidth. From this graph, it can be concluded that, by changing the radius of the circle at the middle, the first resonance of the antenna can be tuned to have different operating regions.

Feed line is a crucial part of the design consideration for antennae operating at microwave frequencies. By changing only the feed line itself, antenna characteristics can be changed significantly. As the current propagation starts from the feed line and the other parts of the antenna depend on the flow of the current through the feed line, Figure 5 shows the response of the antenna for changes in the feed-line thickness "c." For $c = 3$ mm, the antenna performance at first resonance gives response of lower than $-15$ dB with a $-10$ dB bandwidth starting from 5.5 GHz to 5.9 GHz. But this construction fully lacks the second resonance response. Again for $c = 4$ mm, the first resonance is almost as same as the resonance response for $c = 3$ mm. A $-10$ dB bandwidth starting from 7.4 GHz to 7.85 GHz can be seen for the second resonance response. At $c = 5$ mm, a little portion of the first resonance acts below $-10$ dB which is acceptable as a resonance frequency for the antenna. Furthermore, compared to the other constructions, the resonance is wide and physically it will be easier to achieve. For the second resonance, the setup shows a stable and wide bandwidth performance of 0.4 GHz. For $c = 6$ mm, the antenna shows a narrow bandwidth performance at the first resonance starting from 5.55 GHz till 5.95 GHz. The second resonance response is as low as $-35.4$ dB at 7.65 GHz with a bandwidth starting from 7.45 GHz to 7.95 GHz.

By changing the length and width of the partial ground plane, different response can be found. Figure 6 shows the response to the parametric change in the ground plane length “q.” The study is carried out using large steps to find major changes in the resonance response of the antenna. It can be observed that for $q = 50$ mm a total number of 3 resonances can be found in the $S_{11}$ response. The resonance frequencies are at 4.95 GHz, 5.95 GHz, and 7.65 GHz with a bandwidth of 0.3 GHz, 0.2 GHz, and 0.3 GHz, respectively.
With $q = 60$ mm, the antenna shows a narrow bandwidth at the first resonance and comparatively wider bandwidth at the second resonance. The resonance frequencies are at 5.75 GHz and 7.65 GHz with a bandwidth of 0.1 GHz and 0.6 GHz, respectively. Also the response shows a wideband notch in the middle of two resonances. For $q = 70$ mm the antenna resonance response is limited to two frequencies where the first resonance response is at 5.75 GHz with $S_{11}$ response of less than $-22$ dB and the second resonance response is at 7.6 GHz with a reflection coefficient of less than $-18$ dB. For $q = 80$ mm, the antenna gives a wide bandwidth of 0.8 GHz at 5.7 GHz resonance frequency and 0.4 GHz at 7.6 GHz resonance frequency.

Figure 7 shows the response to the parametric change in the ground plane width “$p$”. A step of 10 mm is taken between 30 mm and 60 mm for the parametric studies. For $p = 60$ mm, the antenna frequency response alters dramatically. First resonance frequency cannot be seen for this setup of the antenna, whereas the second frequency shifts about 0.5 GHz from the optimum resonance response of the antenna with a narrow band of 0.25 GHz. First resonance of the antenna becomes very narrow when $p = 50$ mm with resonance response above $-10$ dB. There are two more resonance frequencies situated at 7.15 GHz and 8.55 GHz with a reflection coefficient of $-28$ dB and $-27$ dB, respectively. The bandwidths are 0.4 GHz and 0.6 GHz, respectively. For $p = 40$ mm, the first resonance is amended fully, whereas the second resonance is shifted inwards with a reflection coefficient of $-31$ dB at 7.35 GHz. It can be observed that, for $p = 30$ mm, we find the optimum resonance response with a bandwidth of 0.8 GHz at 5.7 GHz resonance frequency and 0.4 GHz at 7.6 GHz resonance frequency.

4. Results and Discussion

The proposed antenna is measured using Agilent E8362C power network analyzer. The design and simulation of the antenna are carried out using commercially available software HFSS (High Frequency Structure Simulator) by Ansys Corporation. This software uses finite element method (FEM) to calculate the antenna radiation characteristics and the resonance frequency.

Figure 8 shows the simulated and measured $S_{11}$ response of the proposed antenna after optimization yielding the parametric studies above. It can be observed that the simulated result and the measured result tend to agree with each other. However, the measured result shows increased bandwidth at the resonance frequencies compared to the simulated result. At the first resonance the bandwidth is 0.9 GHz starting from 5.4 GHz till 6.3 GHz which is 0.1 GHz increment from the simulated result. Again at the second resonance, the bandwidth of the measured result is 0.9 GHz starting from 7.1 GHz till 8.0 GHz which is 0.5 GHz increment from the simulated resonance response. Although the measured result shows wider bandwidth, nonetheless both of resonance responses are almost at the same frequencies. Although the first mode resonance behaves as depicted in the $S_{11}$ parameter simulation, the second mode resonance bandwidth is increased and the resonance point is shifted from the simulation. This could be due to the higher frequency current leakage by the connecting wire.

Figure 9 shows the surface current distribution of the antenna at two resonance frequencies. It can be seen for both resonance frequencies that the edge of the active microstrip line close to the circle is showing the most intensive current distribution which amounts 64 Am$^{-1}$ for 5.7 GHz and 65.5 Am$^{-1}$ for 7.6 GHz. It is due to the coupling between the circle and feed line. The outer microstrip patch with length “$a$” does not have significant current passing inside of it compared to others, because it is the second parasitic element and stays further from the feed line compared to the parasitic circle. Moreover from the current distribution pattern at the active element, it can be seen that, there are nulls introduced periodically which can be due to the coupling with the parasitic circle. Considering the current distribution at the ground plane, the same periodical null pattern can be found for both resonance frequencies. The ground plane shows...
Figure 9: Surface current distribution of patch and ground plane at (a) 5.7 GHz and (b) 7.6 GHz in Amp/m.

Figure 10: Gain of the proposed microstrip antenna.
a very slim connection with the secondary parasitic element at the upper edge of the antenna. Again for both frequencies, it can be seen that there is a surrounded current distribution pattern within the edges of the parasitic circle, which shows that the first coupling is strong enough to distribute the active elements current to the first passive element.

Figure 10 shows the simulated and measured gain of the antenna. It can be observed that the average simulated gain is bigger than the average measured gain. Moreover, at the WLAN operating frequency the measured gain stays almost the same as the simulated gain which is 6.16 dBi. For the second resonance mode, the measured gain is 2.5 dBi which...
is about 1.6 dBi less than the simulated gain. The measured gain can be affected by the geometry achieved for the antenna. As the antenna characteristics depend more on the coupling between the patch elements, improper coupling can reduce the total gain of the antenna. A fractional bandwidth of 13.5% is measured at the first resonance frequency and a fractional bandwidth of 12% is measured at the second resonance frequency. The VSWR result is shown in Figure 11. It shows, at the resonance frequencies, the VSWR is less than 2 at an average. This shows that the loss due to wave reflection is minimized at the antenna operating region. The proposed antenna characteristics are tabulated in Table 1.

Figures 12 and 13 show the simulated and measured normalized radiation pattern of the antenna, respectively. It can be observed that, in Figures 12(a), 12(b), and 12(c), the co-pol beam of the antenna shows direction properties. However, Figure 12(d) does not follow the same pattern. In Figure 13, we can observe noise is introduced in the co- and cross-pol radiation pattern. The noise is due to the long wire from the VNA till the turn table inside anechoic chamber. As the default minimum scale is set to −60 dB, most of the direction pattern is not observed.

Table 1: Performance of the antenna at resonance frequencies.

<table>
<thead>
<tr>
<th></th>
<th>First resonance</th>
<th>Second resonance</th>
</tr>
</thead>
<tbody>
<tr>
<td>Frequency (GHz)</td>
<td>5.7</td>
<td>7.6</td>
</tr>
<tr>
<td>Bandwidth (GHz)</td>
<td>0.8</td>
<td>0.9</td>
</tr>
<tr>
<td>Gain (dBi)</td>
<td>6.4</td>
<td>4.04</td>
</tr>
</tbody>
</table>

Calibration is performed before measurement. Nonetheless, the difference between the measured and simulated result took place due to the fact that shape of the parasitic element is not achieved exactly as in the simulation. Also the length of the cable used in the measurement shoot leakage current out of its radial plane at higher frequencies.

Figure 14 shows the electrical model of the proposed antenna. The driven modes 1 and 2 RLC circuits represent the patch at two-resonance mode of the antenna. Parasitic elements 1 and 2 RLC circuits depict the two parasitic element
5. Conclusion

Use of parasitic element for obtaining dual mode response is shown in this paper. A novel dual band microstrip antenna for C-band application is presented. The antenna shows coupling response using a circular parasitic element partially coupled with the active feed line. A secondary coupling is shown in this paper using secondary parasitic element and primary parasitic element. A relation between two parasitic elements is shown using the current distribution pattern at the resonances of the antenna. The proposed antenna achieves a \(-10\) dB impedance bandwidth of 800 MHz (from 5.5 GHz to 6.3 GHz) of impedance bandwidth at the lower frequency (WLAN) and 900 MHz (from 7.1 to 8 GHz) of impedance bandwidth at the upper frequency. The measured gains are 6.16 dBi and 2.5 dBi at 5.7 GHz and 7.6 GHz, respectively.

Conflict of Interests

The authors declare that there is no conflict of interests regarding the publication of this paper.

References


